Ordering number : EN6026

GaAs Infrared LED

SPI-238-18

Ultraminiature photointerrupter (single-transistor type)

Features

- GaAs Infrared LED plus Single Phototransistor
- Photo-Interrupter
- Contact type
- Compact type : H4.95 × L6.0 × W5.5mm

Absolute Maximum Ratings at Ta=25°C, 65%RH

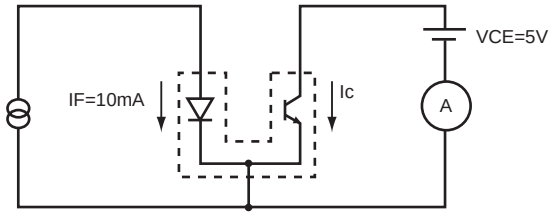
Parameter		Symbol	Rating	Unit
Input LED	Forward Current	I_F	50	mA
	Reverse Voltage	V_R	5	V
	Power Dissipation	P_D	70	mW
Output Phototransistor	Collector-Emitter Voltage	V_{CEO}	20	V
	Emitter-Collector Voltage	V_{ECO}	5	V
	Collector Curren	I_C	20	mA
	Power Dissipation	P_C	70	mW
Operating Temperature		Topr	–20 to +80	°C
Storage Temperature		Tstg	–30 to +85	°C
Soldering Temperature *1		Tsol	260	°C

*1 Soldering conditions : time : max. 3sec; clearance : min. 1mm from lower stay

Electro-Optical Characteristics at Ta=25°C, 65%RH

Parameter		Symbol	Condition	Min.	Typ.	Max.	Unit
Input	Forward Voltage	V_F	I_F=10mA	1.0	1.15	1.4	V
	Reverse Current	I_R	V_R=5V	–	–	10	μA
Output	Dark Current	I_{CEO}	I_F=0mA, V_{CE}=10V	–	10	200	nA
Coupled	Collector Output Current	I_C	I_F=10mA, V_{CE}=5V*1	40	200	400	μA
	Collector Emitter Saturation Voltage	V_{CE}(sat)	I_F=10mA, I_C=20μA	–	–	0.5	V
	Rise Time	tr	V_{CC}=5V, R_L=100Ω I_C=1mA	–	10	–	μs
	Fall Time	tf		–	10	–	μs

*1 Measurement Circuit of Collector Current



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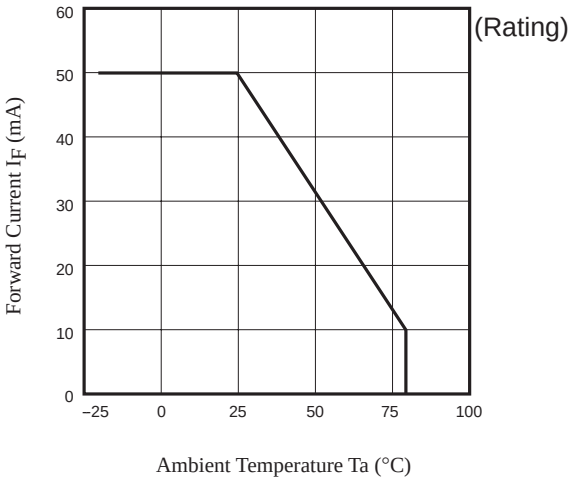
Typical Characteristics

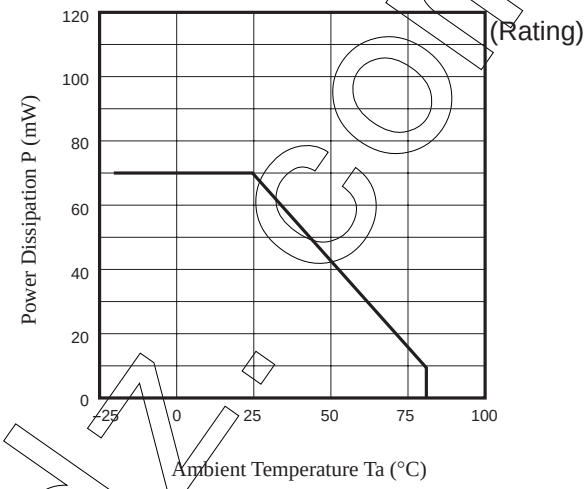
⚠ CAUTION

These numerical value show the electrical and optical characteristics of this product, and not assure this contents.

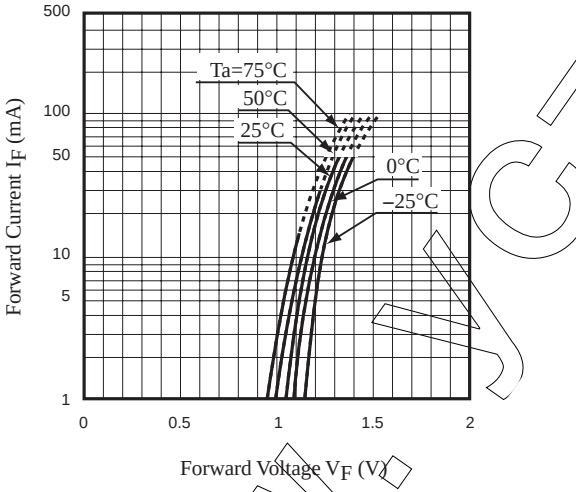
Forward Current vs. Ambient Temperature



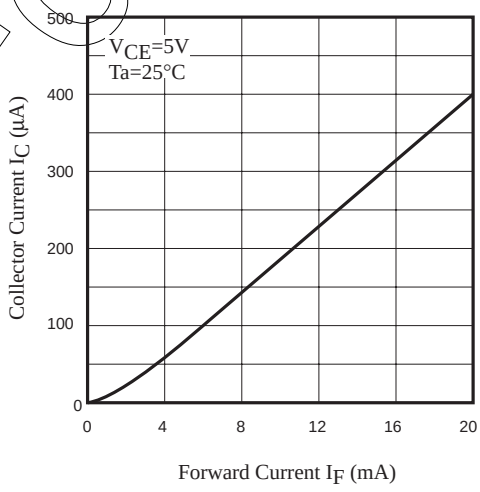
Power Dissipation vs. Ambient Temperature



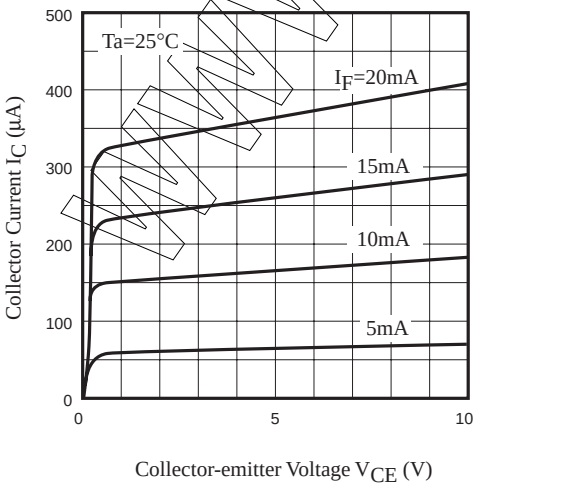
Forward Current vs. Forward Voltage



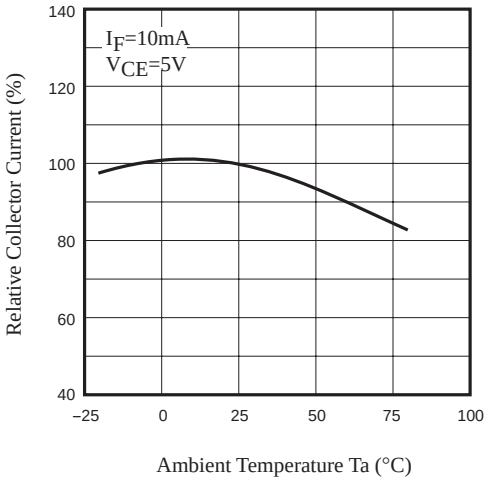
Collector vs. Forward Current



Collector Current vs. Collector-emitter Voltage



Relative Collector Current vs. Ambient Temperature



SANYO Semiconductor

Typical Characteristics

⚠ CAUTION

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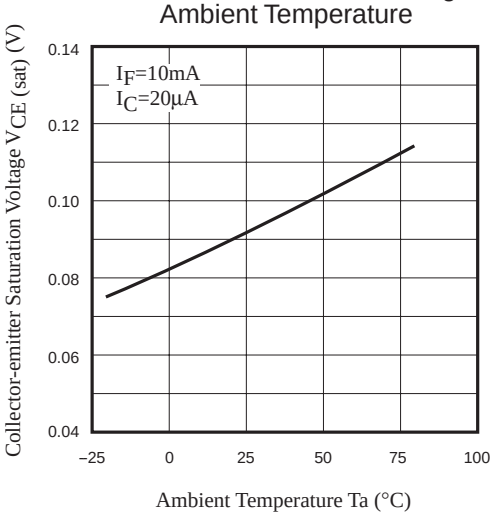
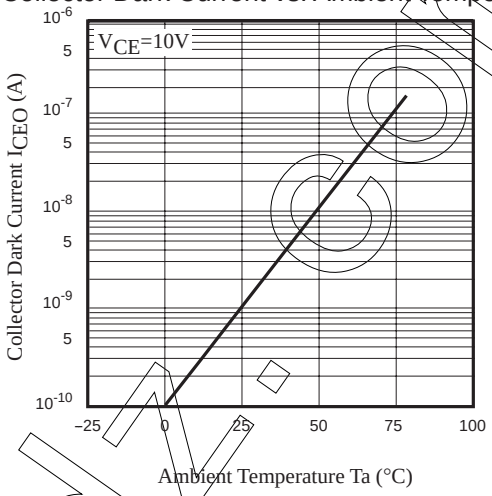
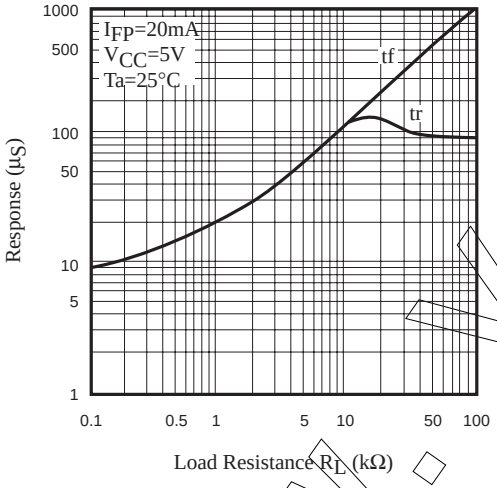
Collector-emitter Saturation Voltage vs. Ambient Temperature



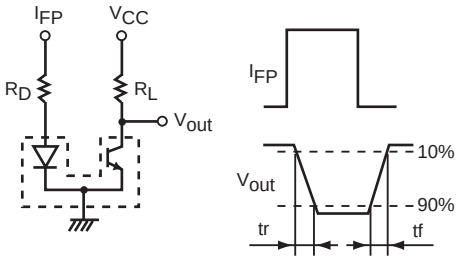
Collector Dark Current vs. Ambient Temperature



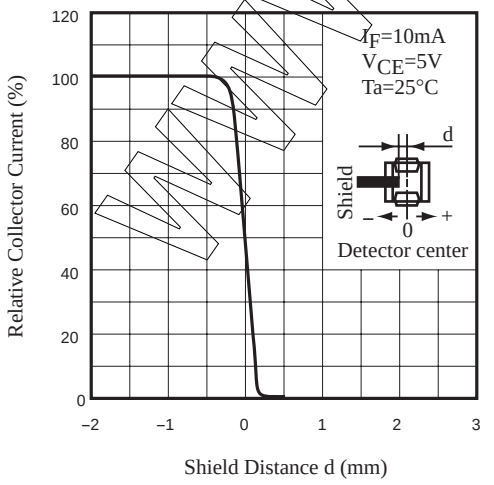
Response Time vs. Load Resistance



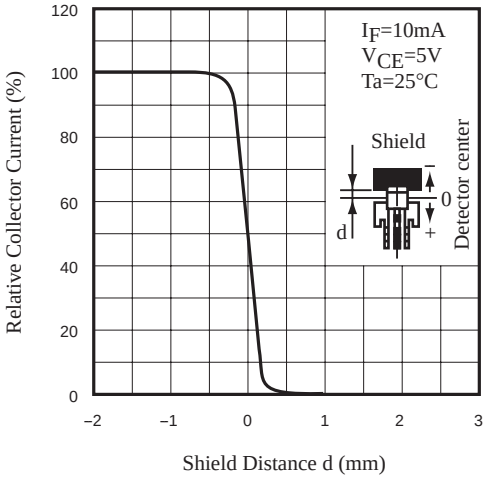
Test Circuit for Response Time



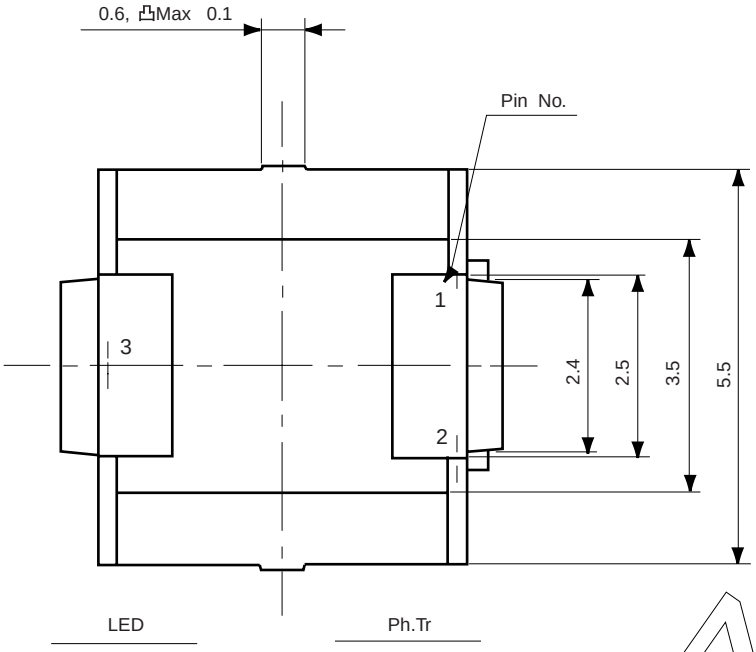
Relative Collector Current vs. Shield Distance (1)



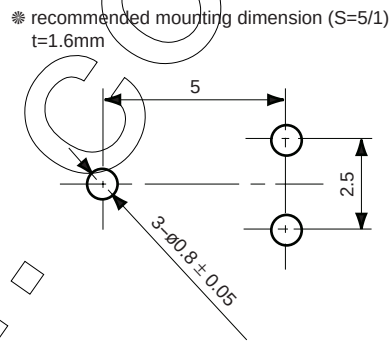
Relative Collector Current vs. Shield Distance (2)

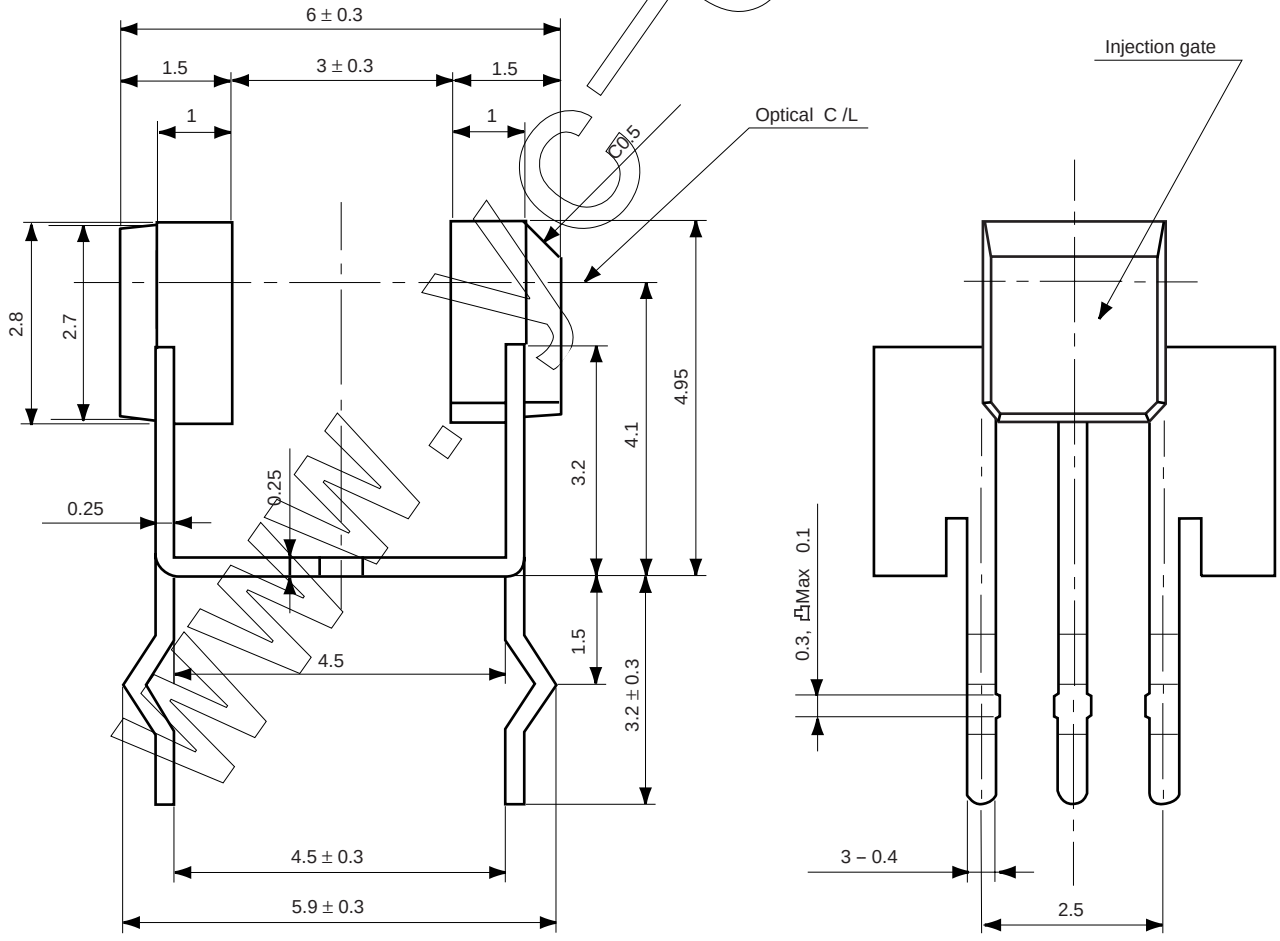


SANYO Semiconductor Data



Pin connection
1. Ph. Tr Collector
2. Common (Cathode)
3. LED Anode





Tolerance : ±0.2
Unit : mm

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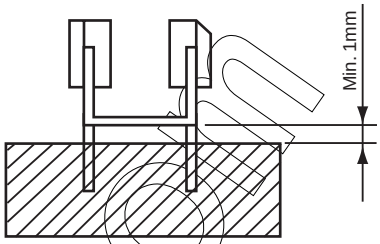
Package dimensions and Pin connection

As stated in the sttached paper. (No.6026 4/6)

Soldering conditions



(1) Temperature : Max. 260°C
(2) Time : Max. 3 sec
(3) Clearance : Min. 1mm from stay (include PCB thickness)

⚠ PRECAUTIONS

(1) Bending a lead should avoid. However, when bending is necessary, take care the next items.
  ① Bending a lead must be done before soldering.
  ② Bending a lead must be done in the states of fixing leads and no stress for the regin part. Because it is possible that stress for the regin part cause troubles such as gold wire breaking and so on.
  ③ A lead must be bend under the stay.
  ④ Do not bend the same position of leads more than twice.
(2) The hole pitch of a circuit board must fit to the recommended mounting dimension.
(3) Two stays coupling LED and Ph. Tr should be isolated from any PCB pattern or any lead.
(4) Take core the following when soldering.
  ① Do not heat a product under any stress (a twist and so on) to leads.
  ② Do not heat a product in the states of operating force to the regin part.
(5) Use the flux which contain no chlorine, have no corrosion and do not need washing.
(6) Be careful that flux or other chemicals do not attach to the luminous surface and passive surface.

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⚠ CAUTION

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Precautionary instructions in handling gallium arsenic products

Special precautions must be taken in handling this product because it contains, gallium arsenic, which is designated as a toxic substance by law. Be sure to adhere strictly to all applicable laws and regulations enacted for this substance, particularly when it comes to disposal.

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